March 2004

# FAIRCHILD

SEMICONDUCTOR®

# ISL9R18120G2 / ISL9R18120P2 / ISL9R18120S3S

# 18A, 1200V Stealth™ Diode

# **General Description**

The ISL9R18120G2, ISL9R18120P2 and ISL9R18120S3S are Stealth<sup>TM</sup> diodes optimized for low loss performance in high frequency hard switched applications. The Stealth<sup>TM</sup> family exhibits low reverse recovery current (I<sub>RM(REC)</sub>) and exceptionally soft recovery under typical operating conditions.

This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low  $I_{RM(REC)}$  and short  $t_a$  phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the Stealth<sup>TM</sup> diode with a 1200V NPT IGBT to provide the most efficient and highest power density design at lower cost.

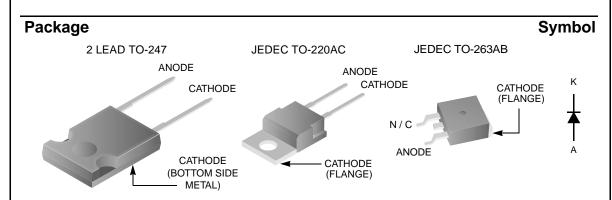
# Features

Soft Recovery ......t<sub>b</sub> / t<sub>a</sub> > 5.0
 Fast Recovery ......t<sub>rr</sub> < 45ns</li>

- Avalanche Energy Rated

# **Applications**

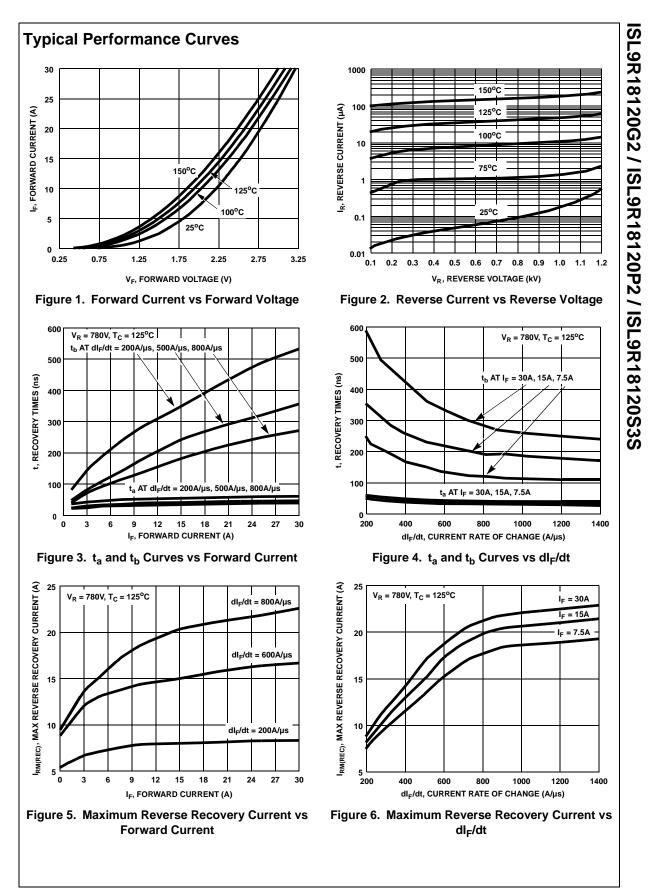
- Switch Mode Power Supplies
- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- SMPS FWD
- Snubber Diode



# Device Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

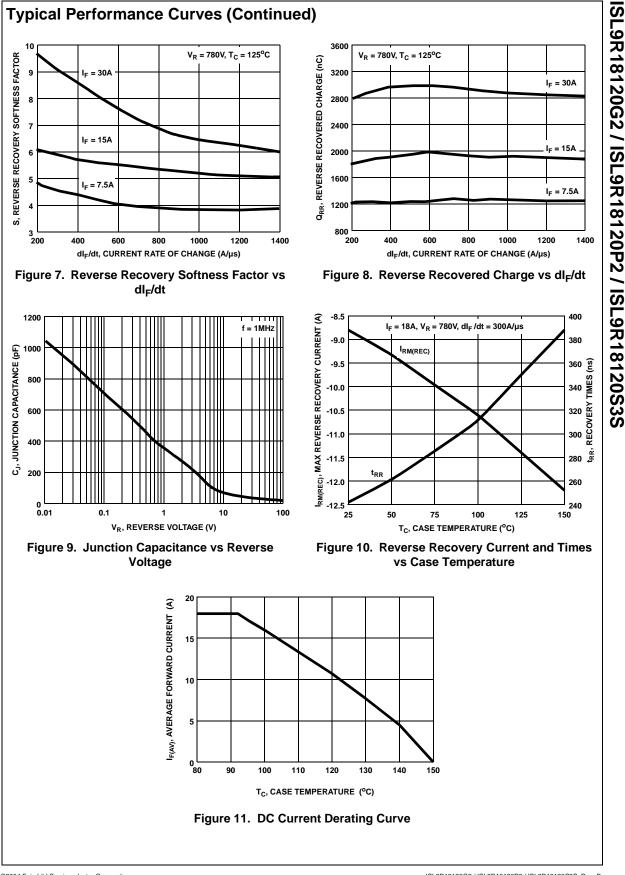
Symbol	Parameter	Ratings	Units	
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	1200	V	
V <sub>RWM</sub>	Working Peak Reverse Voltage	1200	V	
V <sub>R</sub>	DC Blocking Voltage	1200	V	
I <sub>F(AV)</sub>	Average Rectified Forward Current (T <sub>C</sub> = 92°C)	18	А	
I <sub>FRM</sub>	Repetitive Peak Surge Current (20kHz Square Wave)	36	Α	
I <sub>FSM</sub>	Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60Hz)	200	Α	
PD	Power Dissipation	125	W	
E <sub>AVL</sub>	Avalanche Energy (1A, 40mH)	20	mJ	
Г <sub>Ј</sub> , Т <sub>STG</sub>	Operating and Storage Temperature Range	-55 to 150	°C	
ΤL	Maximum Temperature for Soldering			
T <sub>PKG</sub>	Leads at 0.063in (1.6mm) from Case for 10s	300	°C	
	Package Body for 10s, See Application Note AN-7528	260	°C	

Device Marking Device		Package	e Tape Width			Quantity		
R18120G2 ISL9R18120G2		TO-247	N/A			30		
R18120P2 ISL9R18120P2		TO-220AC	N/A		50			
R181	120S3	ISL9R18120S3S	TO-263AB	24mm			800	
Symbol	cal Chai	racteristics T <sub>C</sub> = 25°C u Parameter		noted	Min	Тур	Max	Units
-	Charact					.76		
I <sub>R</sub>	Instantaneous Reverse Current		V <sub>R</sub> = 1200V	T <sub>C</sub> = 25°C	-	-	100	μA
			R	$T_{\rm C} = 125^{\circ}{\rm C}$	-	-	1.0	mA
n State	Charact	eristics					• •	
V <sub>F</sub> Instantaneous Forward Voltage		I <sub>F</sub> = 18A	T <sub>C</sub> = 25°C	-	2.7	3.3	V	
				T <sub>C</sub> = 125°C	-	2.5	3.1	V
ynamic	Charact	eristics						
CJ		apacitance	V <sub>R</sub> = 10V, I <sub>F</sub> = 0A	<b>\</b>	-	69	-	pF
-	g Charac		<u>, ,, , , , , , , , , , , , , , , , , ,</u>					
t <sub>rr</sub>		ecovery Time	$I_{-} = 1A dI_{-}/dt = 1$	100A/µs, V <sub>R</sub> = 30V	_	38	45	ns
٩r					-	60	70	ns
t <sub>rr</sub>	Reverse R	ecovery Time	$I_F = 18A, dI_F/dt = 100A/\mu s, V_R = 30V$ $I_F = 18A,$			300	-	ns
I <sub>RM(REC)</sub>		Reverse Recovery Current	$dI_{F}/dt = 200A/\mu s,$ $V_{R} = 780V, T_{C} = 25^{\circ}C$ $I_{F} = 18A,$ $dI_{F}/dt = 200A/\mu s,$ $V_{R} = 780V,$ $T_{C} = 125^{\circ}C$			6.5	-	A
		ecovered Charge				950	-	nC
t <sub>rr</sub>		ecovery Time				400	-	ns
S		actor (t <sub>b</sub> /t <sub>a</sub> )				7.0	-	-
I <sub>RM(REC)</sub>		Reverse Recovery Current				8.0	-	Α
Q <sub>RR</sub>		ecovered Charge				2.0	-	μC
t <sub>rr</sub>	Reverse R	ecovery Time	I <sub>F</sub> = 18A,	= 18A,			-	ns
S	Softness F	actor (t <sub>b</sub> /t <sub>a</sub> )	$dI_F/dt = 1000A/\mu$	з,	-	5.2	-	-
I <sub>RM(REC)</sub>	Maximum Reverse Recovery Current $V_R = 780V$ ,				-	22	-	Α
Q <sub>RR</sub>	Reverse R	ecovered Charge	T <sub>C</sub> = 125°C			2.1	-	μC
dl <sub>M</sub> /dt	Maximum	di/dt during t <sub>b</sub>			-	370	-	A/µs
	Characte	eristics						
hermal				TO-263		_	1.0	°C/W
	Thermal R	esistance Junction to Case	TO-247, TO-220,	10-200		-		
hermal R <sub>θJC</sub> R <sub>θJA</sub>		esistance Junction to Case esistance Junction to Ambient		10-203	-	-	30	°C/W

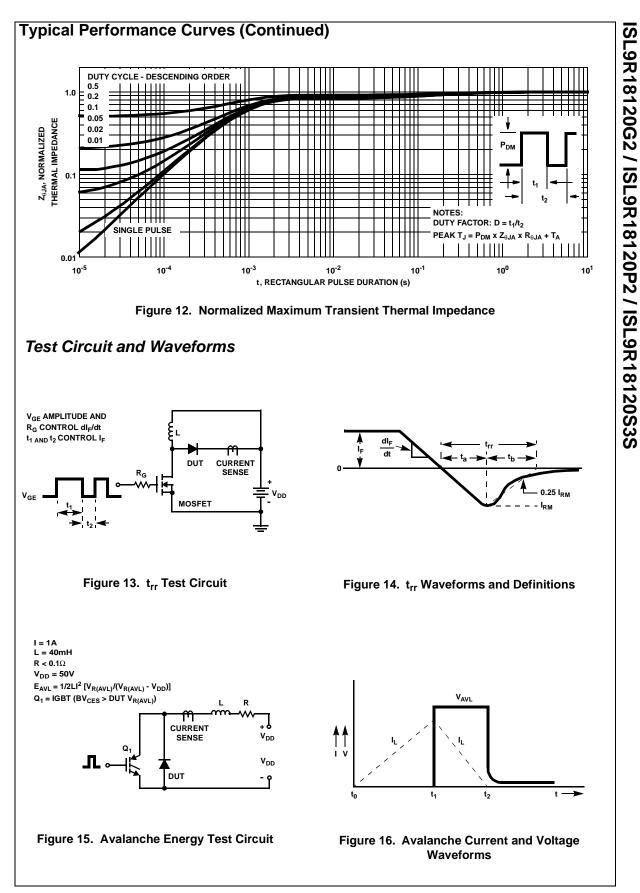


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ISL9R18120G2 / ISL9R18120P2 / ISL9R18120S3S Rev. B



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Programmable Active Droop™		PACMAN™	SPM™	

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Product Status	Definition
Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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	Formative or In Design First Production Full Production



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# ISL9R18120S3S

18A, 1200V STEALTH DIODE, TO263/D2PAK PACKAGE

#### Contents

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#### **General description**

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Formerly developmental type TA49414.

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#### Features

- Soft Recovery . . . . . . . . .  $t_h / t_a > 5.0$
- Fast Recovery ..... t<sub>rr</sub> < 45ns
- Reverse Voltage..... 1200V

# **Related Links**

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### Applications

- Switch Mode Power Supplies
- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- SMPS FWD
- Snubber Diode

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Product status/pricing/packaging BUY

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Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
ISL9R18120S3ST	Full Production	Full Production	\$2.15	<u>TO-263(D2PAK)</u>	2	TAPE REEL	Line 1: <b>\$Y</b> (Fairchild logo) & <b>Z</b> (Asm. Plant Code) & <b>3</b> (3-Digit Date Code) & <b>T</b> (Die Trace Code) Line 2: R18120S3

\* Fairchild 1,000 piece Budgetary Pricing

\*\* A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please

contact a Fairchild distributor to obtain samples

Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product ISL9R18120S3S is available. Click here for more information.

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# **Qualification Support**

Click on a product for detailed qualification data

# Product

ISL9R18120S3ST

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